2SK596S



JFET 20V, 150 to 350μA, 1.0mS, N-Channel

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Features

- · Low output noise voltage: V_{NO}=-110dB max (V_{CC}=4.5V, R_L=1k_Ω, Cin=15pF, V_{IN}=0V, A curve)
- · Especiallysuited for use in condenser microphone for audio equipments and telephones
- · Excellent transient characteristic
- · Adoption of FBET process

Specifications

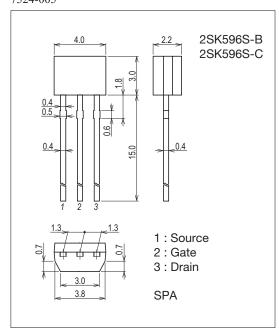
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Gate-to-Drain Voltage	V _{GDO}		-20	V
Gate Current	IG		10	mA
Drain Current	ID		1	mA
Allowable Power Dissipation	PD		100	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Package Dimensions

unit : mm (typ) 7524-005



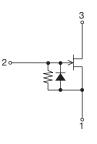
Product & Package Information

Package : SPA
JEITA, JEDEC : SC-72
Minimum Packing Quantity : 500 pcs./bag

Marking



Electrical Connection



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit	
	Symbol Conditions		Rank	min	typ	max	Unit
Gate-to-Drain Breakdown Voltage	V(BR)GDO	I _G =-100μA		-20			V
Cutoff Voltage	VGS(off)	V _{DS} =5V, I _D =1μA			-0.5	-1.0	V
Drain Current	I _{DSS} * V _{DS} =5V, V _{GS} =0V	\\- = \\\\\\ = \\\\\\\\\\\\\\\\\\\\\\\\	В	150		240	μА
		VDS=5V, VGS=0V	С	210		350	
Forward Transfer Admittance	yfs	V _{DS} =5V, V _{GS} =0V, f=1kHz		0.4	1.0		mS
Input Capacitance	Ciss	V _{DS} =5V, V _{GS} =0V, f=1MHz			4.1		рF
Reverse Transfer Capacitance	Crss	V _{DS} =5V, V _{GS} =0V, f=1MHz			0.88		рF
[Ta=25°C, V _{CC} =4.5V, R _L =1kΩ, Cin=15pF, See specified Test Circuit.]							
Voltage Gain	Gy	V _{IN} =10mV, f=1kHz			-3.0		dB
Reduced Voltage Characteristic	ΔGVV	V _{IN} =10mV, f=1kHz, V _{CC} =4.5V \rightarrow 1.5V			-1.0	-3.5	dB
Frequency Characteristic	∆Gvf	f=1kHz → 110Hz				-1.0	dB
Total Harmonic Distortion	THD	V _{IN} =30mV, f=1kHz			1.2		%
Output Noise Voltage	V _{NO}	V _{IN} =0V, A curve				-110	dB

^{* :} The 2SK596S is classified by IDSS as follows : (unit : μ A)

Rank	В	С
IDSS	150 to 240	210 to 350

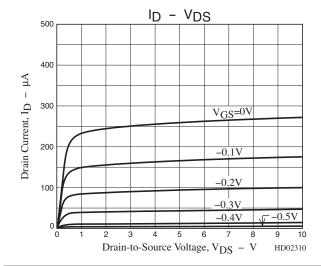
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

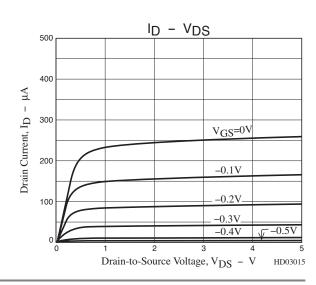
Test Circuit

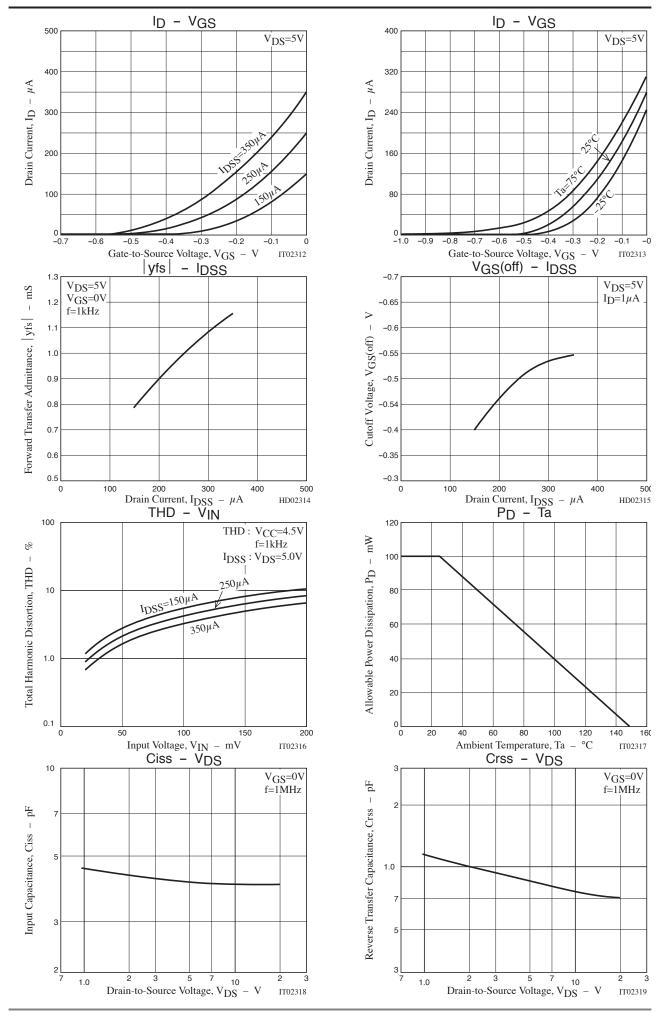
Voltage Gain Frequency Characteristic Harmonic Distortion Reduced Voltage Characteristic

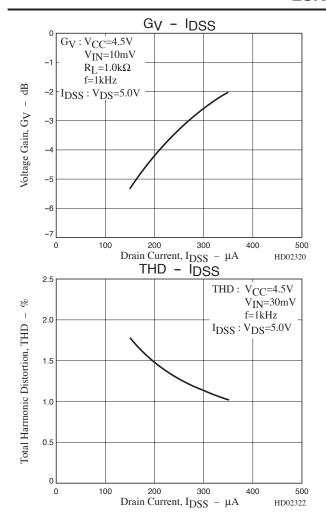
ODERING INFORMATON

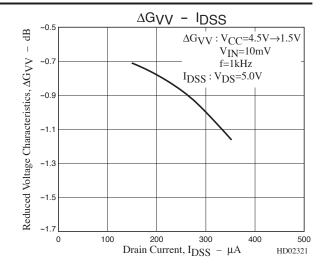
Device	Package	Shipping	memo	
2SK596S-B	SPA	500pcs./bag	- Pb-Free	
2SK596S-C	SPA	500pcs./bag		





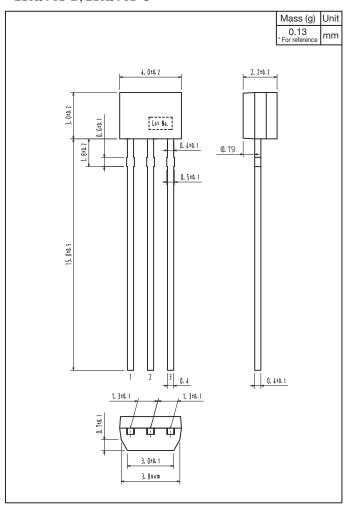






Outline Drawing

2SK596S-B, 2SK596S-C



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